Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-584-4562

	rial:
Plastic	
Overall Length	
	inches and 0.785 inches
Overall Height	
0.200 inches	
Overall Width:	
0.325 inches	
Component Na	ame And Quantity:
4 transistor	
Mounting Meth	lod:
Press fit	
Features Provi	ded:
Hermetically se	aled case
Semiconducto	r Material:
Silicon all transi	stor
Voltage Rating	In Volts Per Characteristic:
60.0 collector to	o base voltage/static/emitter open 1st transistor and 30.0 collector to emitter voltage/static/base open 1st transistor and 5.0
emitter to base	voltage, static, collector open 1st transistor
Current Rating	Per Characteristic:
500.00 milliamp	eres source cutoff current 2nd transistor
Power Rating I	Per Characteristic:
4.6 watts small-	signal input power, common-collector absolute all transistor
Maximum Ope	rating Tempurature Per Measurement Point:
200.0 degrees o	celsius junction
Terminal Type	And Quantity:
14 ribbon	
Shelf Life:	
N/a	
Unit Of Measu	re:
Demilitarizatio	n:
No	
Fiig:	
A110a0	